

Workshop "Rietveld Refinement with Profex"

# Lesson 3: Basics of Rietveld Refinement

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#### **Diffraction Pattern Features**





# «Pattern Features» originate from crystallographic properties:

Pattern Feature	Origin
Peak positions	<ul> <li>Symmetry of the unit cell (space group)</li> <li>Dimensions of the unit cell</li> </ul>
Relative peak intensities	<ul><li>Coordinates of atoms in unit cell</li><li>Species of atoms</li></ul>
Absolute peak intensities	- Abundance of phase
Peak width	<ul><li>Crystallite size</li><li>Micro-Strain in crystal lattice</li></ul>







#### **Rietveld Refinement**

Concept: Fit crystallographic parameters to XRD data

- Unit cell dimensions
- Phase quantities
- Crystallite sizes / shapes
- Atomic coordinates / bond lengths
- Micro-strain in crystal lattice
- Texture effects
- Substitutions / Vacancies



Prof. Hugo Rietveld (1932 - 2016)

No phase identification! All phases must be identified first (unknown phase  $\rightarrow$  no Rietveld refinement) No structure solution! (all crystal structures must be known)

Needs excellent data quality!

#### **Rietveld Refinement**



Optimize structure model, repeat calculation

Minimize differences between calculated and observed pattern by least-squares method







## Step 1: Phase Identification



# Step 1: Phase Identification

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00 -														28.29	843.1	0.3740		981.9	
														32.78				5.0	
7														35.18	530.3	0.1607	681.2		
0														37.80	215.5	0.1636	310.8		
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*	01-077-2248	(Ca F2 )0.75 (Y F3 Ca F2	Calcium Fluorid	le (Elugrite, suc)		0.1	9704 9803	0.785		1.0000	2 40	0.91	19		4-002-2204	AIZ US	Elugrite syn		20.4 43.4
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I	04-004-7480	Ga0.67 Se	Gallium Seleniu	m		0.	9636	0.073	2	1.0000	9.03	0.850	01						
I	04-003-9968	Ga0.5 Ge0.13 Se	Gallium German	nium Selenium		0.	9636	0.070	3	1.0000	8.95	0.849	98						
в	04-014-0211	Si	Silicon			0.	9974	0.078	4	1.0000	4.55	0.848	37						
I	04-003-2846	Al P	Aluminum Phos	sphide		0.	9973	0.071	1	1.0000	4.50	0.84	80						
I	04-006-2647	Ga Sb0.1 P0.9	Gallium Antimo	ny Phosphide		0.	9945	0.076	5	1.0000	8.46	0.84	77						
I	04-008-0619	Cd0.855 La0.095 F2	Cadmium Lanth	hanum Fluoride		0.9	9636	0.065	2	1.0000	11.87	0.84	57 🔺						
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For each phase, a structure model must be obtained.

The model contains:

- Space group
- Cell parameters
- Atomic positions:
  - Scattering factor
  - ✤ Fractional coordinates
  - Thermal displacement parameter

_chemical_formula_sum _chemical_formula_weight _cell_length_a _cell_length_b	'A12 03' 101.96		
_chemical_formula_weight _cell_length_a _cell_length_b	101.96		
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_cell_length_c	12.9933(17)	chemical name systematic	'Calcium Fluoride
_cell_angle_alpha	90	chemical formula sum	'Ca F2'
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	R-3c	cell length c	5.463
	167	cell angle alpha	90
	107	cell angle beta	90
1000		cell angle gamma	90
atom site label		cell formula units Z	4
atom site type symbol		cell_volume	163.04
atom site fract x		symmetry cell setting	cubic
atom site fract v		symmetry space group name H-M	Fm-3m
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		Cal Ca 0.0 0.0 0.0 . 4 a 1.0	

#### Step 3: Rietveld Refinement 1<sup>st</sup> Iteration

- Calculate theoretical diffraction pattern from structure models
- Compare with measured pattern



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## Step 3: Rietveld Refinement Curve Fitting

- Optimize crystallographic parameters in structure models
- Minimize difference between observed and calculated pattern





Step 3: Rietveld Refinement Curve Fitting

Optimize crystallographic parameters in structure models represent sample composition:

- Phase quantities ~
- Cell parameters
- Crystallite size
- Lattice strain
- Atomic coordinates
- Atomic site occupancy factors
- Thermal displacement parameters



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Refined Parameters					
Parameter	Value	ESD			
<ul> <li>Statistics</li> </ul>					
Rwp	7.58				
Rexp	14.01				
χ <sup>2</sup>	0.29				
GoF	0.54				
Background Coefficients	6				
<ul> <li>Global GOALs</li> </ul>					
corundum/sum	0.4958	0.0041			
fluorite/sum	0.5042	0.0041			
<ul> <li>Local GOALs</li> </ul>					
<ul> <li>Corundum_Al2O3</li> </ul>					
Refined Composition	AL12 O18				
A	0.47610	0.00003			
C	1.29960	0.00008			
UNIT	NM				
GrainSize(1,1,1)	124.1	5.0			
UNIT	NM				
▼ Fluorite					
Refined Composition	CA4 F8				
A	0.54677	0.00003			
UNIT	NM				
GrainSize(1,1,1)	42.4413				
UNIT	NM				



Modelling the Peak Profile

Mathematical model to describe the peak profile is needed.

Two different approaches:

- ✤ Use empirical function
  - Pseudo-Voigt
  - Pearson-IIV
  - ♦ ...
- Simulate peak profile from instrument configuration
  - Convolute the effect of every optical element
- = Fundamental Parameters Approach (FPA)



Calculate the peak profile from the device configuration

Take into account the contributions of:

- Source emission profile (X-ray wavelength distribution from Tube)
- Every optical element in the beam path (position, size, etc.)
- Sample contributions (peak broadening due to crystallite size & strain)





Fundamental Parameters Approach (FPA)



www.bruker.com



## Fundamental Parameters Approach (FPA)

**Calculated Peak Profiles** 





## **Fundamental Parameters Approach**

If done properly:



Very good description of the peak profile

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#### Summary: Rietveld Refinement Basics

- Step 1: Phase identification
- Step 2: Obtain crystal structure models for all phases
- Step 3: Rietveld refinement:
  - Calculate XRD pattern from model structure
  - Minimize differences between calculated and measured pattern
- Accurate mathematical description of peak profile required:
  - Classical Rietveld approach: Fit a peak shape function (PV or similar) to reference pattern
  - Fundamental Parameters Approach: Calculate peak profile from device configuration















#### Wrong peak positions

#### Cause:

- Cell parameters
- Sample height displacement
- Instrument misalignment

Solution: Refine cell parameters (and sample height displacement)





#### Wrong absolute intensities

#### Cause:

Weight fraction (scaling)

Solution: Refine phase scale factor





#### Wrong relative intensities

#### Cause:

- Texture / Preferred orientation
- ✤ Graininess
- Atomic species / substitutions
- Atomic coordinates / site occupancies / thermal displacement

#### Solution:

- 1. Check sample quality
- 2. Refine texture
- 3. Full structure refinement (atomic parameters)



#### Wrong peak width

#### Cause:

- Crystallite size
- Micro-strain
- Surface roughness
- Sample transparency

Solution: Refine crystallite size and / or micro-strain







Phase composition: 100%  $AI_2O_3$  Corundum

## Starting Model

#### Refined

Parameter	Value
Unit cell <i>a</i>	0.4775 nm
Unit cell <i>c</i>	1.2993 nm
Crystallite Size	Inf.
Atomic Coordinates Al	0.0 / 0.0 / 0.3522
Atomic Coordinates O	0.3062 / 0.0 / 0.25

Parameter	Value
Unit cell <i>a</i>	0.4760127 +- 0.0000028 nm
Unit cell <i>c</i>	1.2995974 +- 0.0000077 nm
Crystallite Size	1267 +- 138 nm
Atomic Coordinates Al	0.0 / 0.0 / 0.3522
Atomic Coordinates O	0.3062 / 0.0 / 0.25



## Summary: Refinement Strategies





Observation in diffraction pattern	Origin in crystal structure model
Wrong peak positions	Unit cell dimensions Sample height displacement
Wrong absolute intensities	Weight fraction (scaling)
Wrong relative intensities	Preferred orientation Atomic species / substitutions / vacancies Atomic coordinates / displacement parameters
Wrong peak width	Crystallite size Micro-strain

